

ZXT951K

60V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN D-PAK

SUMMARY

$BV_{CEO} = -60V$: $R_{SAT} = 53m\Omega$ typical; $I_C = -6A$

DESCRIPTION

Packaged in the D-PAK outline this high current high performance 60V PNP transistor offers low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.



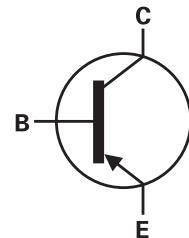
FEATURES

- 6 amps continuous current
- Up to 15 amps peak current
- Low equivalent on resistance
- Low saturation voltages

DPAK

APPLICATIONS

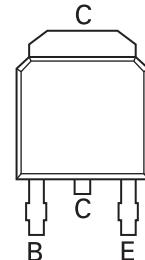
- DC - DC converters
- DC - DC modules
- Power switches
- Motor control
- Automotive circuits
- Inverter circuits



ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL
ZXT951KTC	13"	16mm	2500 units

PINOUT



TOP VIEW

DEVICE MARKING

- ZXT951

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-base voltage	BV_{CBO}	-100	V
Collector-base voltage	BV_{CER}	-100	V
Collector-emitter voltage	BV_{CEO}	-60	V
Emitter-base voltage	BV_{EBO}	-7	V
Peak pulse current	I_{CM}	-15	A
Continuous collector current ^(b)	I_C	-6	A
Base current	I_B	-0.5	A
Power dissipation at $T_A = 25^\circ C$ ^(a)	P_D	2.1	W
Linear derating factor		16.8	$mW/^\circ C$
Power dissipation at $T_A = 25^\circ C$ ^(b)	P_D	3.2	W
Linear derating factor		25.6	$mW/^\circ C$
Power dissipation at $T_A = 25^\circ C$ ^(c)	P_D	4.2	W
Linear derating factor		33.6	$mW/^\circ C$
Operating and storage temperature range	T_j, T_{stg}	-55 to +150	$^\circ C$

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to ambient ^(a)	$R_{\theta JA}$	59	$^\circ C/W$
Junction to ambient ^(b)	$R_{\theta JA}$	39	$^\circ C/W$
Junction to ambient ^(c)	$R_{\theta JA}$	30	$^\circ C/W$

NOTES

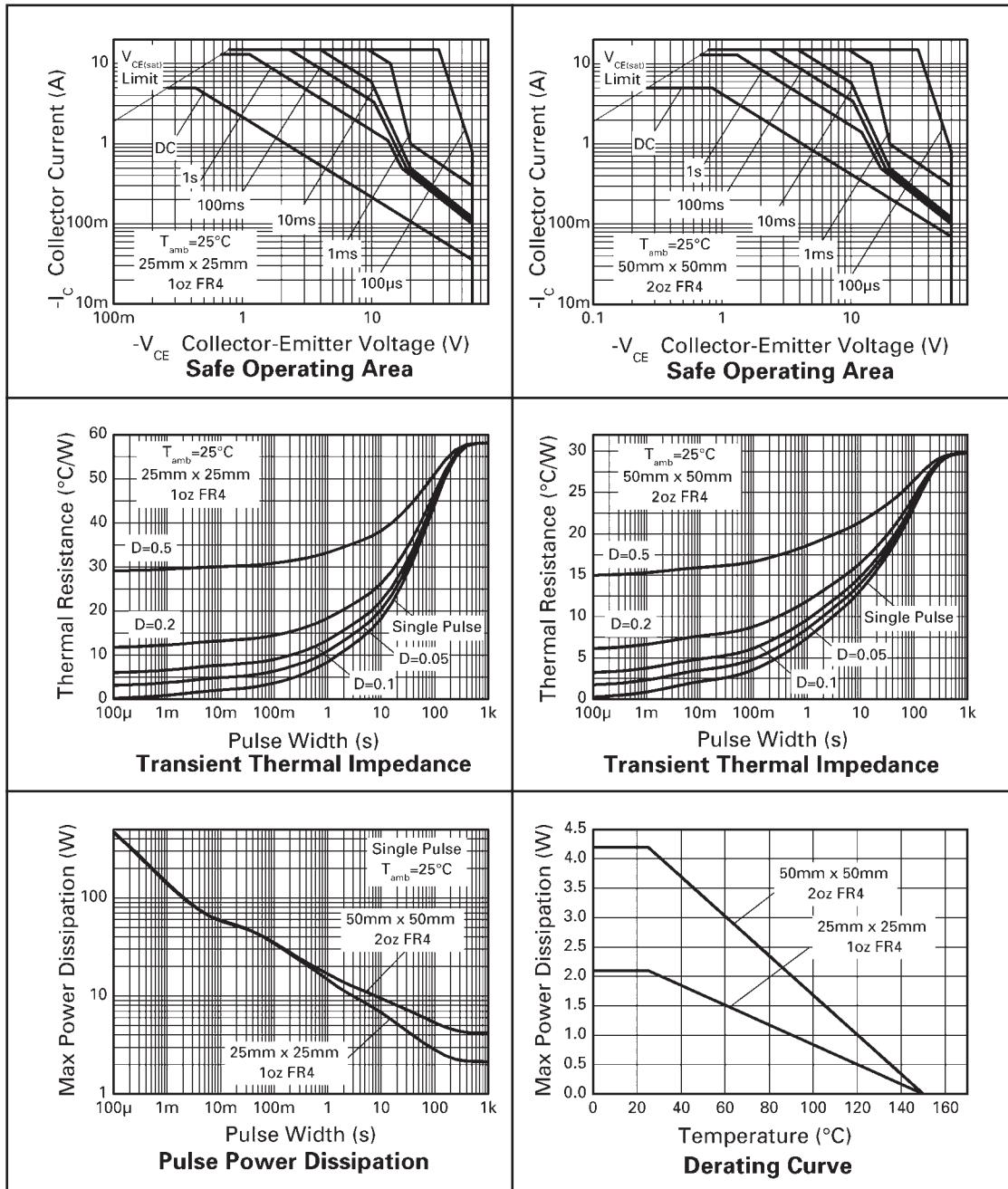
(a) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper in still air conditions.

(b) For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper in still air conditions.

(c) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper in still air conditions.

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TYPICAL CHARACTERISTICS



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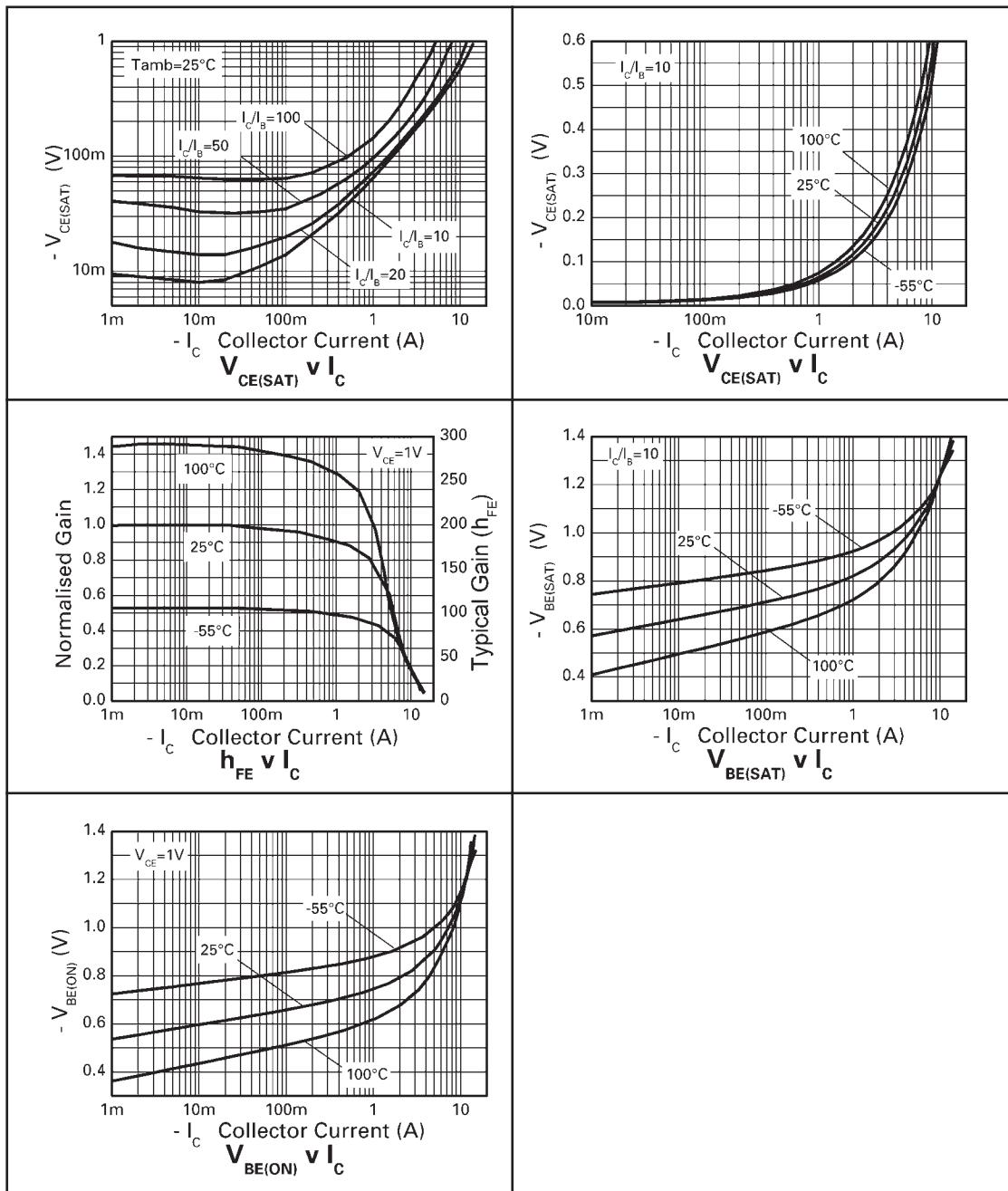
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-base breakdown voltage	BV_{CBO}	-100	-125		V	$I_C=-100\mu A$
Collector-emitter breakdown voltage	BV_{CER}	-100	-125		V	$I_C=-100\mu A, R_{BE} \leq 1k\Omega$
Collector-emitter breakdown voltage	BV_{CEO}	-60	-80		V	$I_C=-10mA^*$
Emitter-base breakdown voltage	BV_{EBO}	-7	-8.1		V	$I_E=-100\mu A$
Collector cut-off current	I_{CBO}		<1	-20	nA	$V_{CB}=-80V$
Collector cut-off current	I_{CER}		<1	-20	nA	$V_{CB}=-80V, R_{BE} \leq 1k\Omega$
Emitter cut-off current	I_{EBO}		<1	-10	nA	$V_{EB}=-6V$
Collector-emitter saturation voltage	$V_{CE(SAT)}$		-13 -60 -115 -315	-25 -90 -165 -400	mV	$I_C=-0.1A, I_B=-10mA^*$ $I_C=-1A, I_B=-100mA^*$ $I_C=-2A, I_B=-200mA^*$ $I_C=-6A, I_B=-600mA^*$
Base-emitter saturation voltage	$V_{BE(SAT)}$		-1.05	-1.2	mV	$I_C=-6A, I_B=-600mA^*$
Base-emitter turn-on voltage	$V_{BE(ON)}$		-0.92	-1.05	mV	$I_C=-6A, V_{CE}=-1V^*$
Static forward current transfer ratio	H_{FE}	100 100 50 15	230 200 110 40	300		$I_C=-10mA, V_{CE}=-1V^*$ $I_C=-2A, V_{CE}=-1V^*$ $I_C=-6A, V_{CE}=-1V^*$ $I_C=-10A, V_{CE}=-1V^*$
Transition frequency	f_T		120		MHz	$I_C=-100mA, V_{CE}=-10V$ $f=50MHz$
Output capacitance	C_{OBO}		74		pF	$V_{CB}=-10V, f=1MHz^*$
Switching times	t_{ON} t_{OFF}		82 350		nS	$I_C=-2A, V_{CC}=-10V,$ $I_{B1}=I_{B2}=-200mA$

* Measured under pulsed conditions. Pulse width $\leq 300\mu s$; duty cycle $\leq 2\%$.

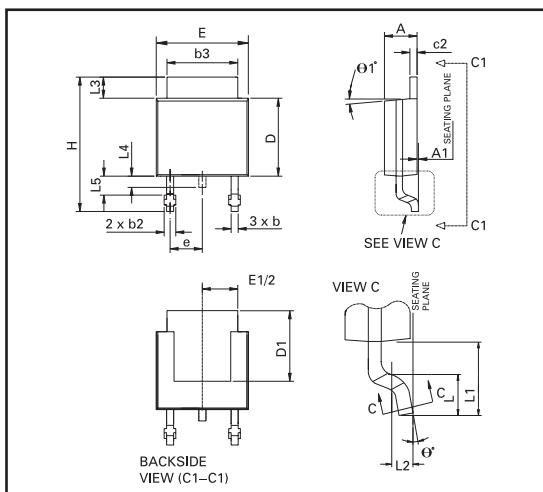
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TYPICAL CHARACTERISTICS



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PACKAGE OUTLINE



Controlling dimensions are in millimeters. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	2.18	2.38	0.086	0.094	e	2.30	BSC	0.090	BSC
A1	—	0.127	—	0.005	H	9.40	10.41	0.370	0.410
b	0.635	0.89	0.025	0.035	L	1.40	1.78	0.055	0.070
b2	0.762	1.114	0.030	0.045	L1	2.74	REF	0.108	REF
b3	5.20	5.46	0.205	0.215	L2	0.051	BSC	0.020	BSC
c	0.457	0.609	0.018	0.024	L3	0.89	1.27	0.035	0.050
c2	0.457	0.584	0.018	0.023	L4	0.635	1.01	0.025	0.040
D	5.97	6.22	0.235	0.245	L5	1.14	1.52	0.045	0.060
D1	5.20	—	0.205	—	theta1°	0°	10°	0°	10°
E	6.35	6.73	0.250	0.265	theta°	0°	15°	0°	15°
E1	4.32	—	0.170	—	—	—	—	—	—

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ISSUE 2 - DECEMBER 2003